



### **60V P-Channel Enhancement Mode MOSFET**

Voltage

-60 V

Current

-15 A

#### **Features**

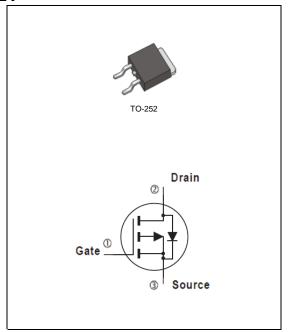
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-10V,I<sub>D</sub>@-7.5A<68mΩ
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ ,  $I_D@-4.0A<85m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

• Case: TO-252 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0104 ounces, 0.297grams



## **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-60	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>C</sub> =25°C	I <sub>D</sub>	-15	А	
	T <sub>C</sub> =100°C		-9.5		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	-60		
Power Dissipation	T <sub>C</sub> =25°C	Po	25	W	
	T <sub>C</sub> =100°C		10		
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	-4.0	Α	
	T <sub>A</sub> =70°C		-3.2	Α	
Power Dissipation	T <sub>A</sub> =25°C	_	2.0	W	
Power Dissipation	T <sub>A</sub> =70°C	Po	1.3		
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	31	mJ	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
Typical Thermal resistance (Note 4,5)	Junction to Case	$R_{\theta JC}$	5.0	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





## **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-60	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250$ uA	-1.0	-1.63	-2.5	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-7.5A	-	55	68	mΩ	
		V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-4.0A	-	73	85		
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}$ =-60V, $V_{GS}$ =0V	-	-	-1.0	uA	
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 7)							
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-30V, I <sub>D</sub> =-7.5A, V <sub>GS</sub> =-10V <sup>(Note 3)</sup>	-	17	-	nC	
Gate-Source Charge	$Q_gs$		-	2.8	-		
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =-10V	-	3.6	-		
Input Capacitance	Ciss		-	879	-	pF	
Output Capacitance	Coss	$V_{DS}$ =-30V, $V_{GS}$ =0V, $f$ =1.0MHZ	-	70	-		
Reverse Transfer Capacitance	Crss	I=1.UIVIHZ	-	47	-		
Turn-On Delay Time	td <sub>(on)</sub>		-	8.4	-	ns	
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =-30V, $I_{D}$ =-1A,	-	30	-		
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =-10V, $R_{G}$ =6 $\Omega$	-	52	-		
Turn-Off Fall Time	t <sub>f</sub>		-	16	-		
Drain-Source Diode							
Maximum Continuous Drain-Source					-15	Α	
Diode Forward Current	I <sub>S</sub>		-	-	-10	A	
Reverse Recovery Time	$V_{SD}$	I <sub>S</sub> =1A,V <sub>GS</sub> =0V	-	-0.73	-1.0	V	

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper
- 6. L=0.1mH,  $I_{AS}$ =-25A,  $V_{GS}$ =-10V,  $V_{DS}$ =-25V,  $R_{G}$ =25 ohm
- 7. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

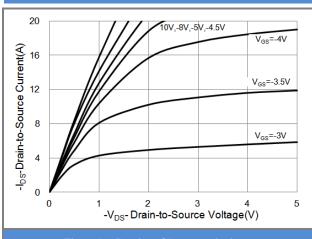
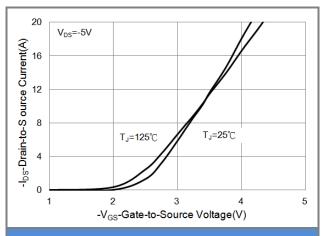


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

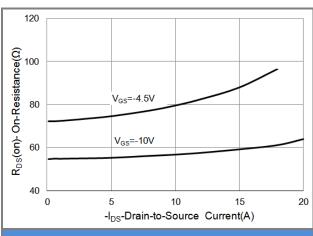


Fig.3 On-Resistance vs. Drain Current

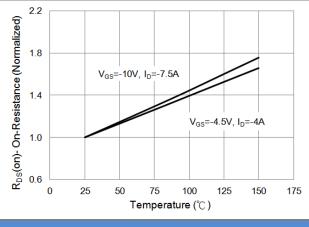


Fig.4 On-Resistance vs. Junction temperature

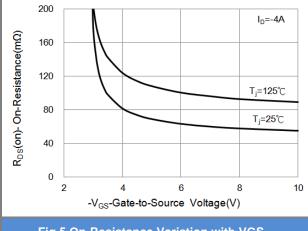


Fig.5 On-Resistance Variation with VGS.

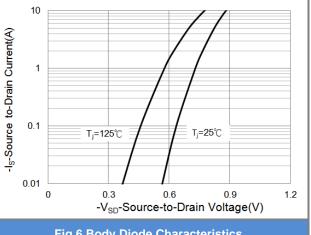
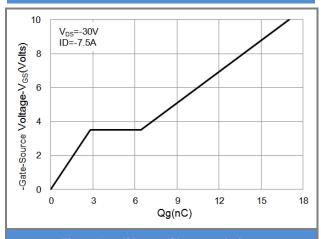


Fig.6 Body Diode Characteristics





#### **TYPICAL CHARACTERISTIC CURVES**



**Fig.7 Gate-Charge Characteristics** 

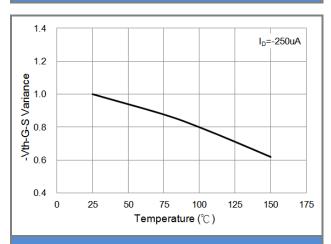


Fig.9 Threshold Voltage Variation with Temperature.

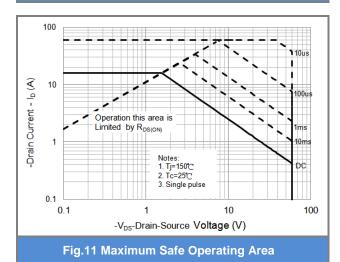


Fig.8 Breakdown Voltage Variation vs. Temperature

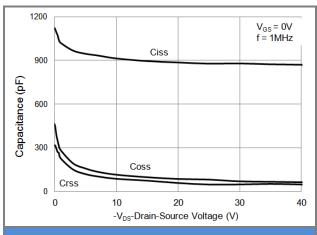
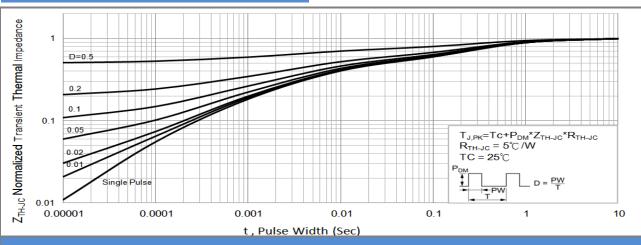


Fig.10 Capacitance vs. Drain-Source Voltage.





### **TYPICAL CHARACTERISTIC CURVES**

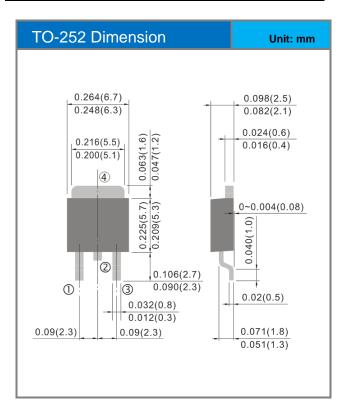


**Fig.12 Normalized Thermal Transient Impedance** 





### **Packaging Information**



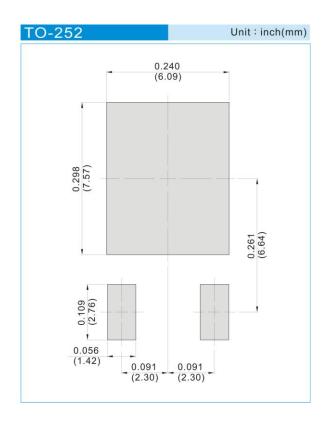




#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version	
PJD15P06A_L2_00001	TO-252	3,000pcs / 13" reel	D15P06A	Halogen free	

### **MOUNTING PAD LAYOUT**







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